

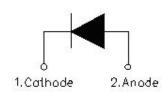
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SDUR60Q60W ULTRAFAST RECTIFIER



Circuit Diagram



Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Plastic Material has UL Flammability Classification
 94V-O
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|---|------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 600 | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle @Tc=70°C, rectangular wave form | 60 | А |
| Peak One Cycle Non-Repetitive Surge Current | I _{FSM} | 8.3ms, Half Sine pulse | 400 | А |

Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +175 | °C |
| Storage Temperature | T _{stg} | - | -55 to +175 | °C |
| Typical Thermal Resistance Junction to Case | R _{θJC} | DC operation | 0.34 | °C/W |
| Approximate Weight | wt | - | 6.28 | g |
| Case Style | TO-247AC | | | |

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Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|--------------------------|------------------|--|--------------|------|-------|
| Forward Voltage Drop* | V _{F1} | @ 30A, Pulse, TJ = 25°C | 1.90 | - | V |
| | V F1 | | | 2.4 | v |
| | V _{F2} | @ 30A, Pulse, T _J = 125°C | 1.60 | _ | V |
| | | @ 60A, Pulse, T _J = 125°C | 2.00 | | - |
| | V _{F3} | @ 30A, Pulse, T _J = 150°C @ 60A, Pulse, T _J = 150°C | 1.50 1.92 | - | V |
| Reverse Current* | I _{R1} | $@V_R = rated V_R T_J = 25^{\circ}C$ | 0.08 | 25 | uA |
| | I _{R2} | $@V_R = rated V_R, T_J = 125^{\circ}C$ | 197 | 500 | uA |
| | I _{R3} | $@V_R$ = rated V_{R} , T_J =150°C | 850 | - | uA |
| Reverse Recovery Time | t _{rr1} | I _F =500mA,I _R =1A,and I _{rm} =250mA, _J T _J =25°C | 36 | 40 | ns |
| Reverse Recovery Time | t _{rr} | | 44 | - | ns |
| Reverse Recovery Charge | Qrr | l | 194 | - | nC |
| Reverse Recovery Current | I _{RRM} | - 11 - 1000, 13 - 20 0 | 8.8 | - | А |
| Reverse Recovery Time | t _{rr} | | 169 | - | ns |
| Reverse Recovery Charge | Qrr | l | 1217 | - | nC |
| Reverse Recovery Current | I _{RRM} | | 14.4 | - | А |
| Reverse Recovery Time | t _{rr} | | 86 | - | ns |
| Reverse Recovery Charge | Qrr | I⊧ = 30A, di⊧/dt = -200A/μs Vℝ = 400V. Τι = 25°C | 206 | - | nC |
| Reverse Recovery Current | I _{RRM} | | 4.8 | - | А |
| Reverse Recovery Time | t _{rr} | | 148 | - | ns |
| Reverse Recovery Charge | Qrr | l | 562 | - | nC |
| Reverse Recovery Current | I _{RRM} | | 7.6 | - | А |
| Reverse Recovery Time | t _{rr} | | 27 | - | ns |
| Reverse Recovery Charge | Qrr | l⊧ = 1A, diғ/dt = -100A/µs VR = 30V, Tյ = 25°C | 20 | - | nC |
| Reverse Recovery Current | I _{RRM} | | 1.5 | - | А |

 $^{\star}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

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SDUR60Q60W

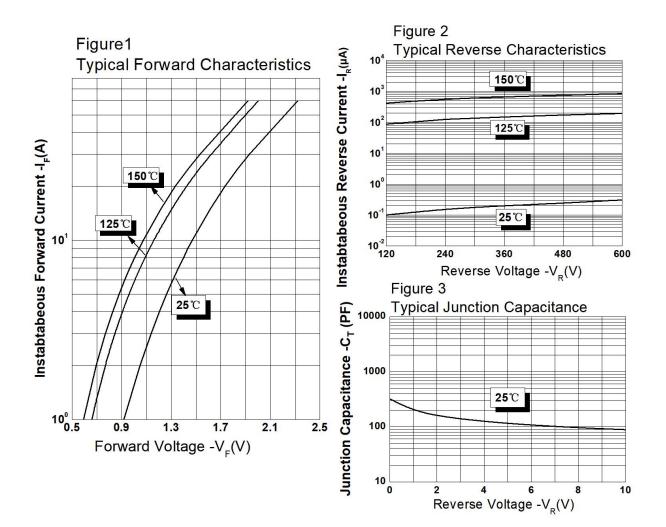




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Ratings and Characteristics Curves

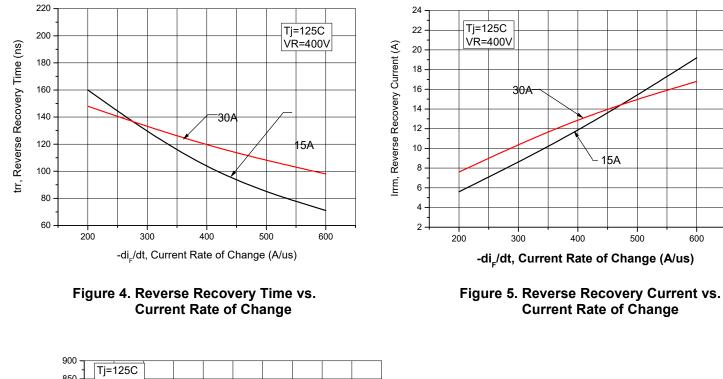


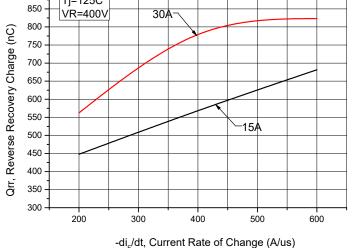


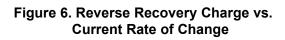
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600







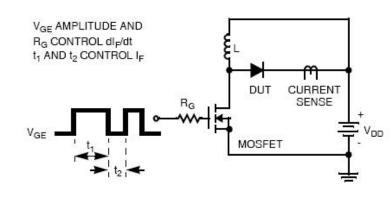
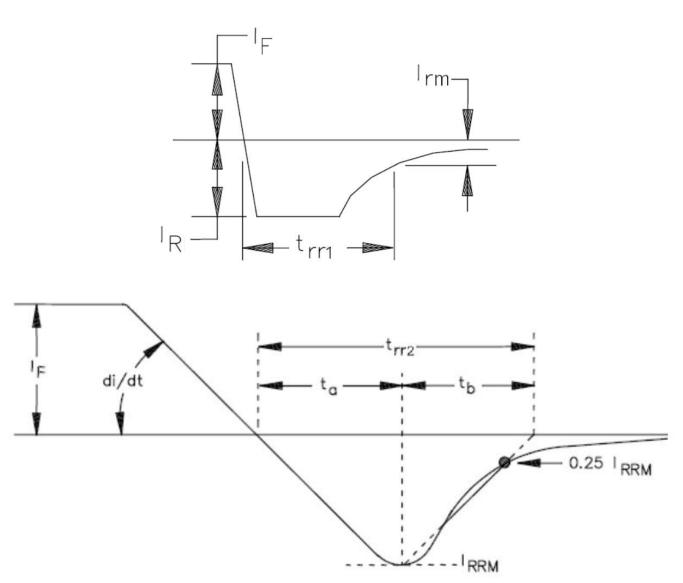


Figure 7. Diode Test Circuit



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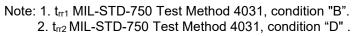


Figure 8 - Reverse Recovery Waveform



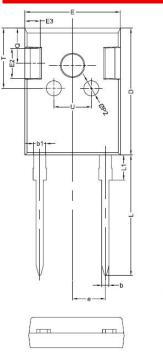
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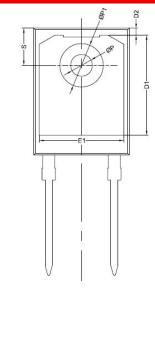


Mechanical Dimensions TO-247AC

- A2

A1



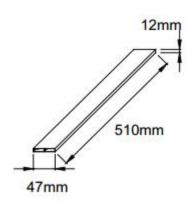


| SYMBOL | Millimeters | | | |
|---------|-------------|-------|-------|--|
| STMBOL | MIN. | TYP. | MAX. | |
| A | 4.80 | 5.00 | 5.20 | |
| A1 | 2.20 | 2.41 | 2.61 | |
| A2 | 1.90 | 2.00 | 2.10 | |
| b | 1.10 | 1.20 | 1.35 | |
| b1 | 1.80 | 2.00 | 2.20 | |
| С | 0.50 | 0.60 | 0.75 | |
| D | 20.30 | 21.00 | 21.20 | |
| D1 | | 16.58 | | |
| D2 E | | 1.17 | | |
| E | 15.60 | 15.80 | 16.00 | |
| E1 | | 14.02 | | |
| E2 | | 5.00 | | |
| E3 | | 2.50 | | |
| е | | 5.44 | | |
| L | 19.42 | 19.92 | 20.42 | |
| L1 | | 4.13 | | |
| Р | 3.50 | 3.60 | 3.70 | |
| P1 | 7.1 | 7.19 | 7.40 | |
| P2 | | 2.50 | | |
| Q | | 5.80 | | |
| Q S | 6.05 | 6.15 | 6.25 | |
| Т | | 10.00 | | |
| U | | 6.20 | | |

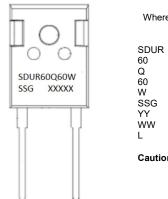
Ordering Information

| Device | Package | Plating | Shipping |
|------------|-------------------|---------|--------------|
| SDUR60Q60W | TO-247AC(Pb-Free) | Pure Sn | 25pcs / tube |

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

| DUR | = Device Type |
|-----|-------------------------|
|) | = Forward Current (60A) |

- = Q
- = Reverse Voltage (600V) = Configuration
- = SSG
- = Year
- = Week = Lot Number
- Cautions: Molding resin Epoxy resin UL:94V-0
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